12-output DB1200ZL Derivative with Integrated 85Ω Terminations

DATASHEET

General Description

The 9ZXL1251 meets the demanding requirements of the Intel DB1200ZL specification, including the critical low-drift requirements of Intel CPUs. It is pin compatible to the 9ZXL1231 and integrates 24 termination resistors, saving 41mm² board area.

Recommended Application

Buffer for Romley, Grantley and Purley Servers, solid state storage and PCIe

Output Features

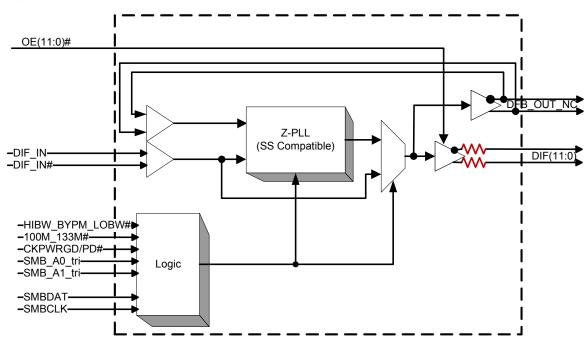
12 LP-HCSL Output Pairs w/integrated terminations (Zo = 85Ω)

Key Specifications

- Cycle-to-cycle jitter <50ps
- Output-to-output skew <50ps
- Input-to-output delay variation <50ps
- PCIe Gen3 phase jitter <1.0ps RMS
- Phase jitter: QPI/UPI >=9.6GB/s <0.2ps rms

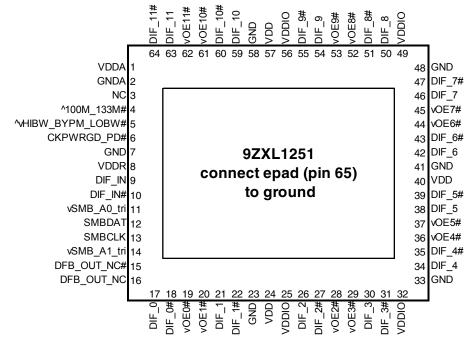
Features/Benefits

- 85Ω Low-power push-pull HCSL outputs; eliminate 24 resistors, save 41mm² of area
- Pin compatible to 9ZX21201 and 9ZXL1231; easy path to power and area savings
- Space-saving 64-pin VFQFPN package
- · Fixed feedback path for 0ps input-to-output delay
- 9 Selectable SMBus Addresses; multiple devices can share the same SMBus Segment
- 12 OE# pins; hardware control of each output
- PLL or bypass mode; supports common and separate clock architectures
- Selectable PLL bandwidth; minimizes jitter peaking in downstream PLL's
- Spread Spectrum Compatible; tracks spreading input clock for low EMI
- -40°C to +85°C device available; supports demanding environmental applications



Block Diagram

Pin Configuration



9 x 9mm VFQFPN package

Note: Pins with ^ prefix have internal 120K pullup Pins with v prefix have internal 120K pulldowm Pins with ^v prefix have internal 120K pullup/pulldown (biased to VDD/2)

Power Management Table

CKPWRGD_PD#	DIF_IN/ DIF_IN#	SMBus EN bit	DIF(11:0)/ DIF(11:0)#	PLL STATE IF NOT IN BYPASS MODE
0	Х	Х	Low/Low	OFF
4	Dunning	0	Low/Low	ON
I	Running	1	Running	ON

Functionality at Power-up (PLL mode)

100M_133M#	DIF_IN MHz	DIF(11:0)
1	100.00	DIF_IN
0	133.33	DIF_IN

Power Connections

	Pin Number		-
VDD	VDDIO	GND	Description
1		2	Analog PLL
8		7	Analog Input
24,40,57	25,32,49,56	23,33,41,48, 58,65	DIF clocks

PLL Operating Mode Readback Table

HiBW_BypM_LoBW#	Byte0, bit 7	Byte 0, bit 6
Low (Low BW)	0	0
Mid (Bypass)	0	1
High (High BW)	1	1

PLL Operating Mode

HiBW_BypM_LoBW#	MODE
Low	PLL Lo BW
Mid	Bypass
High	PLL Hi BW

NOTE: PLL is OFF in Bypass Mode

9ZXL1251 SMBus Addressing

P	in	
SMB_A1_tri	SMB_A0_tri	SMBus Address
0	0	D8
0	М	DA
0	1	DE
М	0	C2
М	М	C4
М	1	C6
1	0	CA
1	М	CC
1	1	CE

Pin Descriptions

PIN #	PIN NAME	TYPE	DESCRIPTION
1	VDDA	PWR	Power for the PLL core.
2	GNDA	GND	Ground pin for the PLL core.
3	NC	N/A	No Connection.
4	^100M_133M#	IN	3.3V Input to select operating frequency. This pin has an internal pull-up resistor. See Functionality Table for Definition
5	^vHIBW_BYPM_LOBW#	LATCHED IN	Trilevel input to select High BW, Bypass or Low BW mode. This pin is biased to VDD/2 (Bypass mode) with internal pull up/pull down resistors. See PLL Operating Mode Table for
6	CKPWRGD_PD#	IN	3.3V Input notifies device to sample latched inputs and start up on first high assertion, or exit Power Down Mode on subsequent assertions. Low enters Power Down Mode.
7	GND	GND	Ground pin.
8	VDDR	PWR	3.3V power for differential input clock (receiver). This VDD should be treated as an analog power rail and filtered appropriately.
9	DIF_IN	IN	HCSL True input
10	 DIF_IN#	IN	HCSL Complementary Input
11	vSMB_A0_tri	IN	SMBus address bit. This is a tri-level input that works in conjunction with the SMB_A1 to decode 1 of 9 SMBus Addresses. It has an internal 120Kohm pull down resistor.
12	SMBDAT	I/O	Data pin of SMBUS circuitry, 5V tolerant
	SMBCLK	IN	Clock pin of SMBUS circuitry, 5V tolerant
14	vSMB_A1_tri	IN	SMBus address bit. This is a tri-level input that works in conjunction with the SMB_A0 to decode 1 of 9 SMBus Addresses. It has an internal 120Kohm pull down resistor.
15	DFB_OUT_NC#	OUT	Complementary half of differential feedback output, provides feedback signal to the PLL for synchronization with input clock to eliminate phase error. This pin should NOT be connected on the circuit board, the feedback is internal to the package.
16	DFB_OUT_NC	OUT	True half of differential feedback output, provides feedback signal to the PLL for synchronization with the input clock to eliminate phase error. This pin should NOT be connected on the circuit board, the feedback is internal to the package.
17	DIF_0	OUT	HCSL true clock output
18	DIF_0#	OUT	HCSL Complementary clock output
19	vOE0#	IN	Active low input for enabling DIF pair 0. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
20	vOE1#	IN	Active low input for enabling DIF pair 1. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
21	DIF_1	OUT	HCSL true clock output
22	DIF_1#	OUT	HCSL Complementary clock output
23	GND	GND	Ground pin.
24	VDD	PWR	Power supply, nominal 3.3V
	VDDIO	PWR	Power supply for differential outputs
26	DIF_2	OUT	HCSL true clock output
27	DIF_2#	OUT	HCSL Complementary clock output
28	vOE2#	IN	Active low input for enabling DIF pair 2. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
29	vOE3#	IN	Active low input for enabling DIF pair 3. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
30	DIF_3	OUT	HCSL true clock output
	DIF_3#	OUT	HCSL Complementary clock output
32	VDDIO	PWR	Power supply for differential outputs
	GND	GND	Ground pin.
34	DIF_4	OUT	HCSL true clock output
-	 DIF_4#	OUT	HCSL Complementary clock output
	vOE4#	IN	Active low input for enabling DIF pair 4. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
37	vOE5#	IN	Active low input for enabling DIF pair 5. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs



Pin Descriptions (cont.)

39 DI 40 VI 41 GI	01F_5 01F_5# /DD	OUT OUT	HCSL true clock output
40 VI 41 GI	/DD	OUT	
41 GI			HCSL Complementary clock output
		PWR	Power supply, nominal 3.3V
40 DI	AND	GND	Ground pin.
42 DI	0IF_6	OUT	HCSL true clock output
43 DI	0IF_6#	OUT	HCSL Complementary clock output
44 vC	OE6#	IN	Active low input for enabling DIF pair 6. This pin has an internal pull-down.
44 VC	OE6#	IIN	1 =disable outputs, 0 = enable outputs
45		IN	Active low input for enabling DIF pair 7. This pin has an internal pull-down.
45 vC	OE7#	IIN	1 =disable outputs, 0 = enable outputs
46 DI	0IF_7	OUT	HCSL true clock output
47 DI	0IF_7#	OUT	HCSL Complementary clock output
48 GI	ND	GND	Ground pin.
49 VI	/DDIO	PWR	Power supply for differential outputs
50 DI	0IF_8	OUT	HCSL true clock output
51 DI	0IF_8#	OUT	HCSL Complementary clock output
50		INI	Active low input for enabling DIF pair 8. This pin has an internal pull-down.
52 vC	OE8#	IN	1 =disable outputs, 0 = enable outputs
50	050#	IN	Active low input for enabling DIF pair 9. This pin has an internal pull-down.
53 vC	OE9#	IIN	1 =disable outputs, 0 = enable outputs
54 DI	0IF_9	OUT	HCSL true clock output
55 DI	0IF_9#	OUT	HCSL Complementary clock output
56 VI	/DDIO	PWR	Power supply for differential outputs
57 VI	′DD	PWR	Power supply, nominal 3.3V
58 GI	ND	GND	Ground pin.
59 DI	0IF_10	OUT	HCSL true clock output
60 DI	0IF_10#	OUT	HCSL Complementary clock output
61 vC	OE10#	IN	Active low input for enabling DIF pair 10. This pin has an internal pull-down.
		IIN	1 =disable outputs, 0 = enable outputs
60	0011#	INI	Active low input for enabling DIF pair 11. This pin has an internal pull-down.
62 vC	OE11#	IN	1 =disable outputs, 0 = enable outputs
63 DI	0IF_11	OUT	HCSL true clock output
64 DI	0IF_11#	OUT	HCSL Complementary clock output
65 ep	pad	GND	epad, connect to ground

Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the 9ZXL1251. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	МАХ	UNITS	NOTES
Supply Voltage	VDDx				4.6	V	1,2
Input Low Voltage	V _{IL}		GND-0.5			V	1
Input High Voltage	V _{IH}	Except for SMBus interface			V _{DD} +0.5	V	1,3
Input High Voltage	VIHSMB	SMBus clock and data pins			5.5	V	1
Storage Temperature	Ts		-65		150	°C	1
Junction Temperature	Tj				125	°C	1
Input ESD protection	ESD prot	Human Body Model	2000			V	1

¹Guaranteed by design and characterization, not 100% tested in production.

² Operation under these conditions is neither implied nor guaranteed.

³ Not to exceed 4.6V.

Electrical Characteristics–DIF_IN Clock Input Parameters

T_{AMB} = T_{COM} or T_{IND}, unless noted., Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Input Crossover Voltage - DIF_IN	V _{CROSS}	Cross Over Voltage	150		900	mV	1
Input Swing - DIF_IN	V _{SWING}	Differential value	300			mV	1
Input Slew Rate - DIF_IN	dv/dt	Measured differentially	0.4		8	V/ns	1,2
Input Leakage Current	I _{IN}	$V_{IN} = V_{DD}, V_{IN} = GND$	-5		5	uA	
Input Duty Cycle	d _{tin}	Measurement from differential wavefrom	45		55	%	1
Input Jitter - Cycle to Cycle	J _{DIFIn}	Differential Measurement	0		125	ps	1

¹ Guaranteed by design and characterization, not 100% tested in production.

²Slew rate measured through +/-75mV window centered around differential zero

Electrical Characteristics-SMBus

T_{AMB} = T_{COM} or T_{IND}, unless noted., Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

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PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
SMBus Input Low Voltage	VILSMB				0.8	V	
SMBus Input High Voltage	VIHSMB		2.1		V _{DDSMB}	V	
SMBus Output Low Voltage	V _{OLSMB}	@ I _{PULLUP}			0.4	V	
SMBus Sink Current	I _{PULLUP}	@ V _{OL}	4			mA	
Nominal Bus Voltage	V _{DDSMB}		2.7		3.6	V	1
SCLK/SDATA Rise Time	t _{RSMB}	(Max VIL - 0.15) to (Min VIH + 0.15)			1000	ns	1
SCLK/SDATA Fall Time	t _{FSMB}	(Min VIH + 0.15) to (Max VIL - 0.15)			300	ns	1
SMBus Operating Frequency	f _{MAXSMB}	Maximum SMBus operating frequency			400	kHz	5

¹Guaranteed by design and characterization, not 100% tested in production.

²Control input must be monotonic from 20% to 80% of input swing.

³Time from deassertion until outputs are >200 mV

⁴DIF_IN input

⁵The differential input clock must be running for the SMBus to be active

Electrical Characteristics–Input/Supply/Common Parameters

T_{AMB} = T_{COM} or T_{IND}, unless noted., Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	IV Voltages per normal operation conditions, See Te CONDITIONS	MIN	TYP	MAX	UNITS	NOTE
Supply Voltage	VDDx	Supply voltage, except VDDIO	3.135	3.3	3.465	V	
Output Supply Voltage	VDDIO	Supply voltage for DIF outputs, if present	0.95	1.05	3.465	V	
Ambient Operating		Commercial range (T _{COM})	0		70	°C	
Temperature	T _{AMB}	Industrial range (T _{IND})	-40		85	°C	
Input High Voltage	V _{IH}	Single-ended inputs, except SMBus, tri-level inputs	2		V _{DD} + 0.3	V	
Input Low Voltage	V _{IL}	Single-ended inputs, except SMBus, tri-level inputs	GND - 0.3		0.8	V	
Input High Voltage	V _{IHTRI}	Tri-Level Inputs	2.2		V _{DD} + 0.3	V	
Input Mid Voltage	VIMTRI	Tri-Level Inputs	1.2	VDD/2	1.8	V	
Input Low Voltage	VILTRI	Tri-Level Inputs	GND - 0.3		0.8	V	
	I _{IN}	Single-ended inputs, $V_{IN} = GND$, $V_{IN} = VDD$	-5		5	uA	
Input Current Input Frequency	I _{INP}	$\label{eq:VIN} \begin{array}{l} Single-ended \ inputs \\ V_{IN} = 0 \ V; \ Inputs \ with \ internal \ pull-up \ resistors \\ V_{IN} = VDD; \ Inputs \ with \ internal \ pull-down \ resistors \end{array}$	-200		200	uA	
	F _{ibyp}	$V_{DD} = 3.3 V$, Bypass mode	33		150	MHz	
Input Frequency	F _{ipll}	$V_{DD} = 3.3 V$, 100MHz PLL mode	90	100.00	110	MHz	
	F _{ipll}	V _{DD} = 3.3 V, 133.33MHz PLL mode	DIO 3.135 3.3 3.465 V f present 0.95 1.05 3.465 V w 0 70 $^{\circ}$ C 4.0 85 $^{\circ}$ C $s, tri-level$ 2 $V_{DD} + 0.3$ V $s, tri-level$ $GND - 0.3$ 0.8 V 2.2 $V_{DD} + 0.3$ V 2.2 $V_{DD} + 0.3$ V 1.2 $VDD/2$ 1.8 V $GND - 0.3$ 0.8 V $I_{IN} = VDD$ -5 5 uA $J_{IN} = VDD$ -5 5 uA $I_{IN} = VDD$ -5 5 uA $I_{IN} = VDD$ -5 5 uA $I_{IN} = 1.5$ 200 uA MHz $I_{IN} = 1.5$ 5 pF pF $I_{IN} = 1.5$ 2.7 pF pF $I_{II} = 1.5$ 2.7 pF PF				
Pin Inductance	L _{pin}				7	nH	1
	CIN	Logic Inputs, except DIF_IN	1.5		5	pF	1
Capacitance	C _{INDIF_IN}	DIF_IN differential clock inputs	1.5		2.7	pF	1,4
	C _{OUT}	Output pin capacitance			6	pF	1
Clk Stabilization	T _{STAB}	From V _{DD} Power-Up and after input clock stabilization or de-assertion of PD# to 1st clock		0.18	1.8	ms	1,2
Input SS Modulation Frequency PCIe	f _{MODINPCIe}	Allowable Frequency for PCIe Applications (Triangular Modulation)	30		33	kHz	
OE# Latency	t _{LATOE#}	DIF start after OE# assertion DIF stop after OE# deassertion	4		10	clocks	1,2,3
Tdrive_PD#	t _{DRVPD}	DIF output enable after PD# de-assertion			300	us	1,3
Tfall	t _F	Fall time of control inputs			5	ns	2
Trise	t _R	Rise time of control inputs			5	ns	2

¹Guaranteed by design and characterization, not 100% tested in production.

²Control input must be monotonic from 20% to 80% of input swing.

 $^3\text{Time}$ from deassertion until outputs are >200 mV

⁴DIF_IN input

Electrical Characteristics–DIF Low Power HCSL Outputs

T_{AMB} = T_{COM} or T_{IND}, unless noted., Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS		TYP	MAX	UNITS	NOTES
Slew rate	dV/dt	T _{AMB} = T _{COM} , Scope averaging on		3.3	4	V/ns	1,2,3
Siew rate	av/at	$T_{AMB} = T_{IND}$ Scope averaging on	1.6	2.8	4.1	V/ns	1,2,3
Slew rate matching	∆dV/dt	Slew rate matching, Scope averaging on		7	20	%	1,2,4
Voltage High	VHigh	Statistical measurement on single-ended signal using oscilloscope math function. (Scope		754	850	mV	
Voltage Low	VLow	averaging on)	-150	62	150		
Max Voltage	Vmax	Measurement on single ended signal using		868	1150	mV	
Min Voltage	Vmin	absolute value. (Scope averaging off)		-64		IIIV	
Crossing Voltage (abs)	Vcross_abs	Scope averaging off	250	453	550	mV	1,5
Crossing Voltage (var)	∆-Vcross	Scope averaging off		17	140	mV	1,6

¹Guaranteed by design and characterization, not 100% tested in production.

² Measured from differential waveform

³ Slew rate is measured through the Vswing voltage range centered around differential 0V. This results in a +/-150mV window around differential 0V.

⁴ Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a +/-75mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

⁵ Vcross is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

⁶ The total variation of all Vcross measurements in any particular system. Note that this is a subset of Vcross_min/max (Vcross absolute) allowed. The intent is to limit Vcross induced modulation by setting △-Vcross to be smaller than Vcross absolute.

⁷ At default SMBus settings.

Electrical Characteristics–Current Consumption

T_{AMB} = T_{COM} or T_{IND}, unless noted., Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
		VDDA, PLL Mode@100MHz		13.4	20	mA	1
	DDA	VDDA, PLL Bypass Mode@100MHz		4.8	8	mA	1
Operating Supply Current	I _{DD}	All other VDD pins		16	25	mA	
	I _{DDIO}	VDDIO for DIF outputs, if applicable		81	95	mA	
		VDDA, PLL Mode@100MHz		3	5	mA	1
Device Device Overset	IDDA	VDDA, PLL Bypass Mode@100MHz		3	5	mA	1
Power Down Current	I _{DD}	All other VDD pins		0.14	1	mA	
	I _{DDIO}	VDDIO for DIF outputs, if applicable		0.01	0.3	mA	

^{1.} Includes VDDR if applicable

Electrical Characteristics–Skew and Differential Jitter Parameters

T_{AMB} = T_{COM} or T_{IND}, unless noted., Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

AMB - I COM OI I IND, dillood I	Com of TIND, unless noted., Supply voltages per normal operation conditions, See Test Loads for Loading Conditions						
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
CLK_IN, DIF[x:0]	t _{SPO_PLL}	Input-to-Output Skew in PLL mode @100MHz, nominal temperature and voltage	-100	3	100	ps	1,2,4,5,8
CLK_IN, DIF[x:0]	t _{PD_BYP}	Input-to-Output Skew in Bypass mode @100MHz, nominal temperature and voltage	2.5	3.6	4.5	ns	1,2,3,5,8
CLK_IN, DIF[x:0]	t _{DSPO_PLL}	Input-to-Output Skew Varation in PLL mode @100MHz, across voltage and temperature	-50	0	50	ps	1,2,3,5,8
CLK_IN, DIF[x:0]		Input-to-Output Skew Varation in Bypass mode @100MHz, across voltage and temperature, $T_{AMB} = T_{COM}$	-250		250	ps	1,2,3,5,8
	t _{DSPO_BYP}	Input-to-Output Skew Varation in Bypass mode @100MHz, across voltage and temperature, $T_{AMB} = T_{IND}$	-350		350	ps	1,2,3,5,8
		Output-to-Output Skew across all outputs @100MHz, T _{AMB} = T _{COM}		36	50	ps	1,2,3,8
DIF[x:0]	t _{skew_all}	Output-to-Output Skew across all outputs @100MHz, T _{AMB} = T _{IND}		38	65	ps	1,2,3,8
PLL Jitter Peaking	j _{peak-hibw}	LOBW#_BYPASS_HIBW = 1	0	1.2	2.5	dB	7,8
PLL Jitter Peaking	j _{peak-lobw}	LOBW#_BYPASS_HIBW = 0	0	0.8	2	dB	7,8
PLL Bandwidth	pll _{HIBW}	LOBW#_BYPASS_HIBW = 1	2	3	4	MHz	8,9
PLL Bandwidth	pll _{LOBW}	LOBW#_BYPASS_HIBW = 0	0.7	1.1	1.4	MHz	8,9
Duty Cycle	t _{DC}	Measured differentially, PLL Mode	45	50	55	%	1
Duty Cycle Distortion	t _{DCD}	Measured differentially, Bypass Mode @100MHz	-1.5	-0.6	0	%	1,10
Jitter, Cycle to cycle	t	PLL mode		25	50	ps	1,11
	t _{jcyc-cyc}	Additive Jitter in Bypass Mode		1	5	ps	1,11

Notes for preceding table:

¹ Measured into fixed 2 pF load cap. Input to output skew is measured at the first output edge following the corresponding input.

² Measured from differential cross-point to differential cross-point. This parameter can be tuned with external feedback path, if present.

³ All Bypass Mode Input-to-Output specs refer to the timing between an input edge and the specific output edge created by it.

- ⁴ This parameter is deterministic for a given device
- ⁵ Measured with scope averaging on to find mean value.

^{6.}t is the period of the input clock

⁷ Measured as maximum pass band gain. At frequencies within the loop BW, highest point of magnification is called PLL jitter peaking.

^{8.} Guaranteed by design and characterization, not 100% tested in production.

⁹ Measured at 3 db down or half power point.

¹⁰ Duty cycle distortion is the difference in duty cycle between the output and the input clock when the device is operated in bypass mode.

¹¹ Measured from differential waveform

Electrical Characteristics–Phase Jitter Parameters

T_{AMB} = T_{COM} or T_{IND}, unless noted., Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	IND.LIMIT	UNITS	Notes
	t _{jphPCleG1}	PCIe Gen 1		36	49	86	ps (p-p)	1,2,3
	t _{jphPCleG2}	PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz		1.2	1.6	3	ps (rms)	1,2
		PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)		2.2	2.8	3.1	ps (rms)	1,2
Phase Jitter, PLL Mode	t _{jphPCleG3}	PCIe Gen 3 (PLL BW of 2-4MHz, CDR = 10MHz)		0.56	0.63	1	ps (rms)	1,2,4
		QPI & SMI (100MHz or 133MHz, 4.8Gb/s, 6.4Gb/s 12UI)		0.22	0.48	0.5	ps (rms)	1,4
	t _{jphQPI_SMI}	QPI & SMI (100MHz, 8.0Gb/s, 12UI)		0.15	0.28	0.3	ps (rms)	1,4
		QPI & SMI (100MHz, 9.6Gb/s, 12UI)		0.11	0.17	0.2	ps (rms)	1,4
	t _{jphPCleG1}	PCIe Gen 1		0.0	0.8	n/a	ps (p-p)	1,2,3
		PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz		0.1	0.2	n/a	ps (rms)	1,2,5
	t _{jphPCleG2}	PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)		0.4	0.5	n/a	ps (rms)	1,2,5
<i>Additive</i> Phase Jitter, Bypass mode	t _{jphPCleG3}	PCIe Gen 3 (PLL BW of 2-4 or 2-5 MHz, CDR = 10MHz)		0.0	0.0	n/a	ps (rms)	1,2,4,5
Bypass mode		QPI & SMI (100MHz or 133MHz, 4.8Gb/s, 6.4Gb/s 12UI)		0.11	0.2	n/a	ps (rms)	1,4,5
	t _{jphQPI_SMI}	QPI & SMI (100MHz, 8.0Gb/s, 12UI)		0.00	0.01	n/a	ps (rms)	1,4,5
		QPI & SMI (100MHz, 9.6Gb/s, 12UI)		0.00	0.01	n/a	ps (rms)	1,4,5

¹ Applies to all outputs.

² See http://www.pcisig.com for complete specs

³ Sample size of at least 100K cycles. This figures extrapolates to 108ps pk-pk @ 1M cycles for a BER of 1-12.

⁴ Calculated from Intel-supplied Clock Jitter Tool v 1.6.3

⁵ For RMS figures, additive jitter is calculated by solving the following equation: Additive jitter = SQRT[(total jitter)^2 - (input jitter)^2]

Clock Periods–Differential Outputs with Spread Spectrum Disabled

			Measurement Window								
SSC OFF	Contor	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock			
	Center Freq. MHz	-c2c jitter AbsPer Min	-SSC Short-Term Average Min	- ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long-Term Average Max	+SSC Short-Term Average Max	+c2c jitter AbsPer Max	Units	Notes	
DIF	100.00	9.94900		9.99900	10.00000	10.00100		10.05100	ns	1,2,3	
DIF	133.33	7.44925		7.49925	7.50000	7.50075		7.55075	ns	1,2,4	

Clock Periods–Differential Outputs with Spread Spectrum Enabled

			Measurement Window							
SSC ON	Center Freq. MHz	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
		-c2c jitter AbsPer Min	-SSC Short-Term Average Min	- ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long-Term Average Max	+SSC Short-Term Average Max	+c2c jitter AbsPer Max	Units	Notes
DIF	99.75	9.94906	9.99906	10.02406	10.02506	10.02607	10.05107	10.10107	ns	1,2,3
DIF	133.00	7.44930	7.49930	7.51805	7.51880	7.51955	7.53830	7.58830	ns	1,2,4

Notes:

¹Guaranteed by design and characterization, not 100% tested in production.

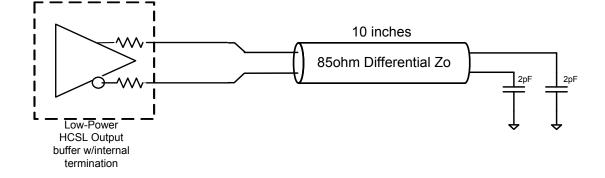
² All Long Term Accuracy specifications are guaranteed with the assumption that the input clock complies with CK420BQ/CK410B+ accuracy requirements (+/-100ppm). The 9ZXL1251 itself does not contribute to ppm error.

³ Driven by SRC output of main clock, 100 MHz PLL Mode or Bypass mode

⁴ Driven by CPU output of main clock, 133 MHz PLL Mode or Bypass mode

Differential Output Terminations

DIF Zo (Ω)	Rs (Ω)
100	NA
85	0



() IDT

General SMBus Serial Interface Information for 9ZXL1251

How to Write

- Controller (host) sends a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will **acknowledge**
- Controller (host) sends the byte count = X
- IDT clock will acknowledge
- Controller (host) starts sending Byte N through Byte N+X-1
- IDT clock will acknowledge each byte one at a time
- Controller (host) sends a Stop bit

	Index Blo	ock \	Write Operation
Controller (Host)		IDT (Slave/Receiver)
Т	starT bit		
Slave A	Address		
WR	WRite		
			ACK
Beginning	g Byte = N		
			ACK
Data Byte	Count = X		
			ACK
Beginnin	g Byte N		
			ACK
0		×	
0		X Byte	0
0		e	0
			0
Byte N	+ X - 1		
			ACK
Р	stoP bit		

How to Read

- Controller (host) will send a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) will send a separate start bit
- Controller (host) sends the read address
- IDT clock will acknowledge
- IDT clock will send the data byte count = X
- IDT clock sends Byte N+X-1
- IDT clock sends Byte 0 through Byte X (if X_(H) was written to Byte 8)
- · Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- Controller (host) will send a stop bit

	Index Block R	lead C	Operation
Controlle	r (Host)		IDT
Т	starT bit		
SI	ave Address		
WR	WRite		
			ACK
Begi	nning Byte = N		
			ACK
RT	Repeat starT		
SI	ave Address		
RD	ReaD		
			ACK
			Data Byte Count=X
	ACK		
			Beginning Byte N
	ACK		
		e	0
	0	X Byte	0
	0	×	0
	0		
			Byte N + X - 1
Ν	Not acknowledge		
Р	stoP bit		

SMBusTable: PLL Mode, and Frequency Select Register

		buc, and frequency of							
Byte	e 0 Pin #	Name	Control Function	Туре	0	1	Default		
Bit 7	5	PLL Mode 1	PLL Operating Mode Rd back 1	R	See PLL Op	See PLL Operating Mode			
Bit 6	5	PLL Mode 0	PLL Operating Mode Rd back 0	R	Readba	Latch			
Bit 5			Reserved						
Bit 4			Reserved						
Bit 3		PLL_SW_EN	Enable S/W control of PLL BW	RW	HW Latch	SMBus Control	0		
Bit 2		PLL Mode 1	PLL Operating Mode 1	RW	See PLL Op	erating Mode	1		
Bit 1		PLL Mode 0	PLL Operating Mode 1	RW	Readba	1			
Bit 0	4	100M_133M#	Frequency Select Readback	R	133MHz	100MHz	Latch		

Note: Setting bit 3 to '1' allows the user to overide the Latch value from pin 5 via use of bits 2 and 1. Use the values from the PLL Operating Mode Readback Table. Note that Bits 7 and 6 will keep the value originally latched on pin 5. A warm reset of the system will have to accomplished if the user changes these bits.

SMBusTable: Output Control Register

Byte	1 Pin #	Name	Control Function	Туре	0	1	Default
Bit 7	47/46	DIF_7_En	Output Control - '0' overrides OE# pin	RW			1
Bit 6	43/42	DIF_6_En	Output Control - '0' overrides OE# pin	RW		Enable	1
Bit 5	39/38	DIF_5_En	Output Control - '0' overrides OE# pin	RW			1
Bit 4	35/34	DIF_4_En	Output Control - '0' overrides OE# pin	RW	Low/Low		1
Bit 3	30/31	DIF_3_En	Output Control - '0' overrides OE# pin	RW	LOW/LOW		1
Bit 2	26/27	DIF_2_En	Output Control - '0' overrides OE# pin	RW			1
Bit 1	21/22	21/22 DIF_1_En	Output Control - '0' overrides OE# pin	RW			1
Bit 0	17/18	DIF_0_En	Output Control - '0' overrides OE# pin	RW			1

SMBusTable: Output Control Register

Byte	2	Pin # Name		Control Function	Туре	0	1	Default		
Bit 7				Reserved				0		
Bit 6				Reserved						
Bit 5				Reserved						
Bit 4				Reserved						
Bit 3	6	4/63	DIF_11_En	Output Control - '0' overrides OE# pin	RW			1		
Bit 2	5	9/60	DIF_10_En	Output Control - '0' overrides OE# pin	RW		Enable	1		
Bit 1	5	4/55	DIF_9_En	Output Control - '0' overrides OE# pin	RW	Low/Low	Enable	1		
Bit 0	5	0/51	DIF_8_En	Output Control - '0' overrides OE# pin	RW		1			

SMBusTable: Reserved Register

Byte 3	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7			Reserved				0
Bit 6			Reserved				0
Bit 5			Reserved				0
Bit 4			Reserved				0
Bit 3			Reserved				0
Bit 2			Reserved				0
Bit 1			Reserved				0
Bit 0			Reserved				0

SMBusTable: Reserved Register

Byte) 4	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7				Reserved				0
Bit 6			Reserved					
Bit 5			Reserved					0
Bit 4				Reserved				0
Bit 3				Reserved				0
Bit 2				Reserved				0
Bit 1				Reserved				0
Bit 0				Reserved				0



SMBusTable: Vendor & Revision ID Register

Byte 5		Name	Control Function	Туре	0	1	Default
Bit 7	-	RID3		R			Х
Bit 6	-	RID2	REVISION ID	R	A rev = 0000	Х	
Bit 5	-	RID1	$\frac{R}{R}$	= 0000	Х		
Bit 4	-	RID0		R		Х	
Bit 3	-	VID3		R	-	-	0
Bit 2	-	VID2	VENDOR ID	R	-	-	0
Bit 1	-	VID1	VENDORID	R	-	-	0
Bit 0	-	VID0		R	-	-	1

SMBusTable: DEVICE ID

Byte 6	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7	-	D	evice ID 7 (MSB)	R			1
Bit 6	-		Device ID 6	R			1
Bit 5	-		Device ID 5	R			1
Bit 4	-		Device ID 4		1251 is 251 Decimal		1
Bit 3	-		Device ID 3		or F	B Hex	1
Bit 2	-		Device ID 2	R			0
Bit 1	-		Device ID 1	R			1
Bit 0	-		Device ID 0	R			1

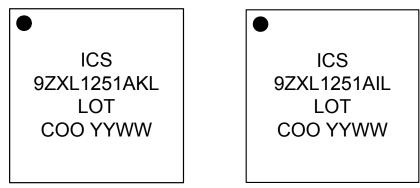
SMBusTable: Byte Count Register

Byte	97	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7			Reserved				0	
Bit 6			Reserved				0	
Bit 5			Reserved					
Bit 4		-	BC4		RW			0
Bit 3		-	BC3	Writing to this register configures how	RW	Default value	is 8 hex, so 9	1
Bit 2		-	BC2	5 S	RW	bytes (0 to 8) v	vill be read back	0
Bit 1		-	BC1	many bytes will be read back.	RW	by de	efault.	0
Bit 0		-	BC0		RW			0

SMBusTable: Reserved Register

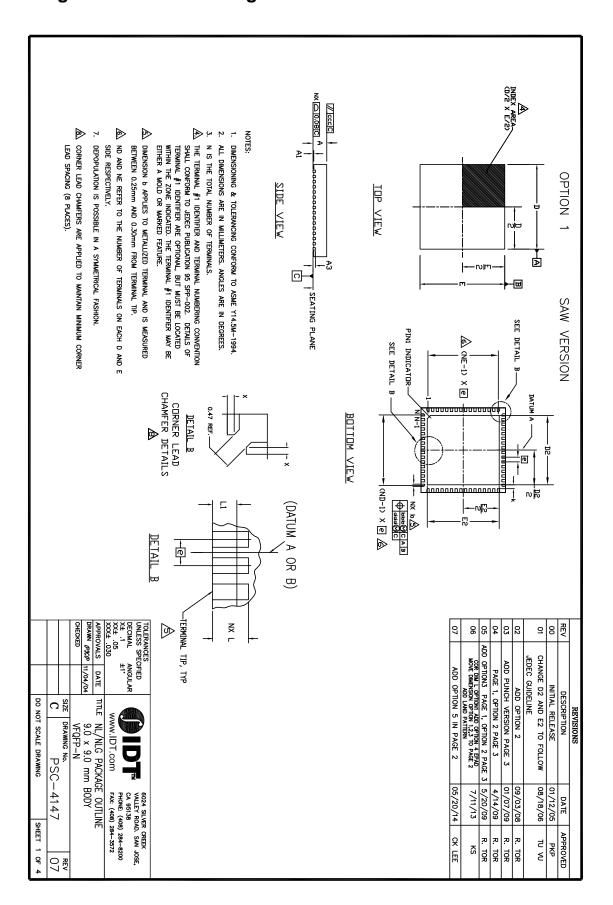
Byte	e 8	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7				Reserved				0
Bit 6			Reserved					0
Bit 5				Reserved				0
Bit 4				Reserved				0
Bit 3				Reserved				0
Bit 2				Reserved				0
Bit 1				Reserved				0
Bit 0				Reserved				0

Marking Diagram



Notes:

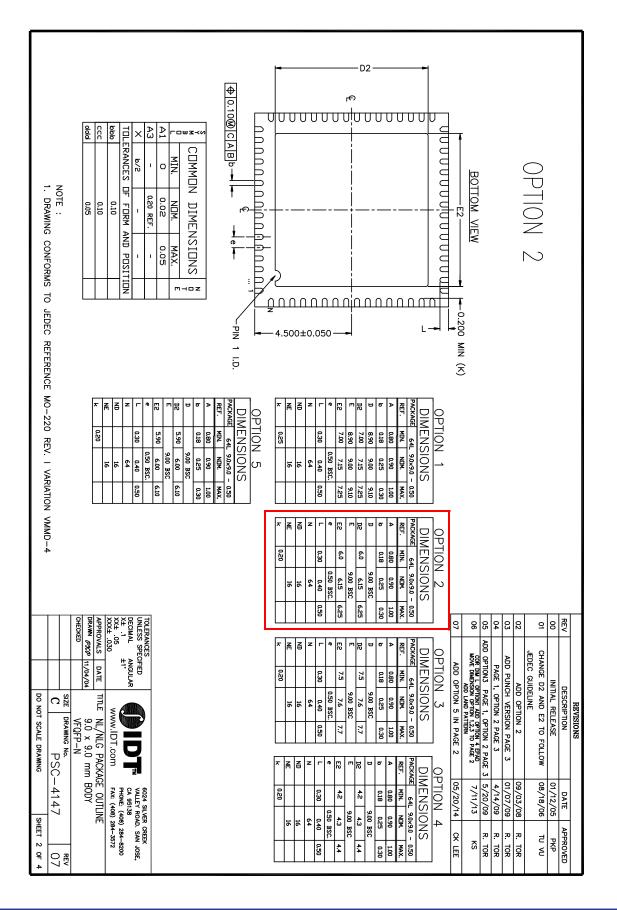
- 1. "I" denotes industrial temperature grade.
- 2. "L" denotes RoHS compliant package.
- 3. "LOT" denotes the lot number.
- 4. "COO" denotes country of origin.
- 5. "YYWW" is the last two digits of the year and week that the part was assembled.

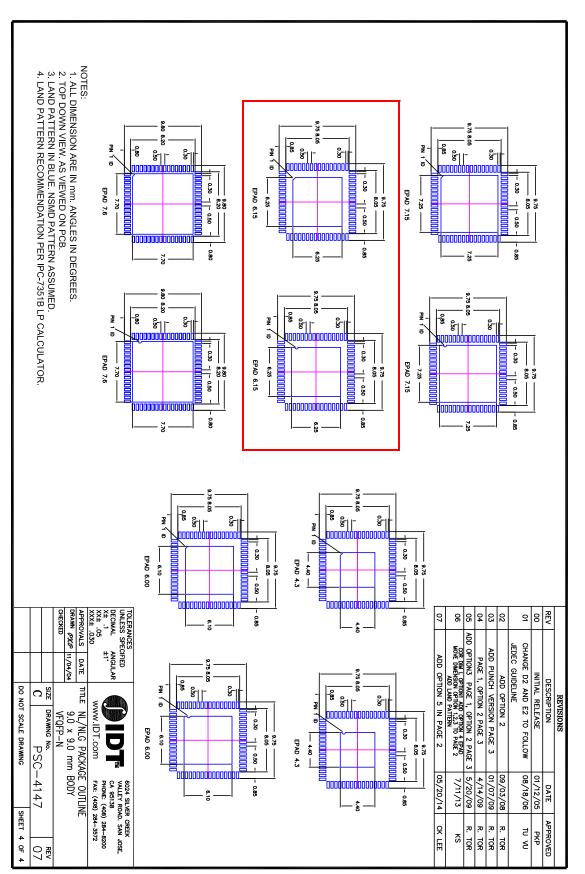


NLG64 Package Outline and Package Dimensions

9ZXL1251 DATASHEET

NLG64 Package Outline and Package Dimensions, cont. Use Option 2 dimensions table.





NLG64 Package Outline and Package Dimensions, cont. Use EPAD 6.15 option

Ordering Information

Part / O	rder Number	Shipping Package	Package	Temperature
9ZXL	1251AKLF	Trays	64-pin VFQFPN	0 to +70°C
9ZXL1	251AKLFT	Tape and Reel	64-pin VFQFPN	0 to +70°C
9ZXL1	251AKILF	Trays	64-pin VFQFPN	-40 to +85°C
9ZXL1	251AKILFT	Tape and Reel	64-pin VFQFPN	-40 to +85°C

"LF" suffix to the part number denotes Pb-Free configuration, RoHS compliant.

"A" is the device revision designator (will not correlate with the datasheet revision).

Revision History

Re	ev.	Issuer	Issue Date	Description	Page #
	4	RDW	7/23/2015	Update to final and Release	Various
I	3	RDW	11/20/2015	 Updated QPI references to QPI/UPI Updated DIF_IN table to match PCI SIG specification, no silicon change 	1,6



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